

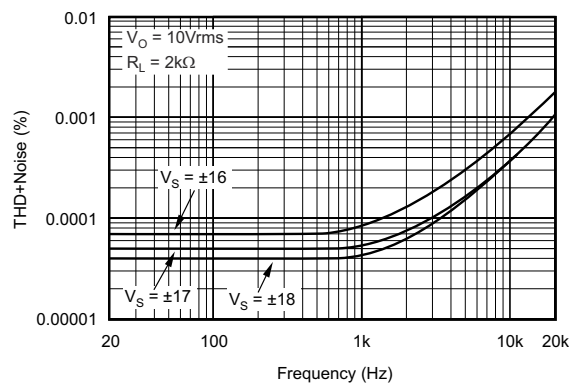
# OPAx134 High-Performance, SoundPlus™ Audio Operational Amplifiers

## 1 Features

- Excellent sound quality
- Ultra-low distortion: 0.00008%
- Low noise:  $8\text{nV}/\sqrt{\text{Hz}}$
- True FET-input:  $I_B = 5\text{pA}$
- High speed:
  - Slew rate:  $20\text{V}/\mu\text{s}$
  - Bandwidth:  $8\text{MHz}$
- High open-loop gain:  $120\text{dB}$  ( $2\text{k}\Omega$ )
- Wide supply range:  $\pm 2.5\text{V}$  to  $\pm 18\text{V}$
- Single, dual, and quad versions

## 2 Applications

- Professional audio and music
- Line drivers
- Line receivers
- Multimedia audio
- Active filters
- Preamplifiers
- Integrators
- Crossover networks



**THD+Noise vs Frequency**

## 3 Description

The OPA134, OPA2134, and OPA4134 (OPAx134) series are ultra-low distortion, low-noise operational amplifiers fully specified for audio applications. A true FET input stage is incorporated to provide excellent sound quality and speed for exceptional audio performance. This feature, in combination with high output drive capability and excellent dc performance, allows for use in a wide variety of demanding applications. In addition, the OPAx134 series has a wide output swing, to within 1V of the rails, allowing increased headroom and making these devices an excellent choice for use in any audio circuit.

The OPAx134 SoundPlus™ audio operational amplifiers are easy to use and free from phase-inversion and the overload problems often found in common FET-input operational amplifiers. The devices can be operated from  $\pm 2.5\text{V}$  to  $\pm 18\text{V}$  power supplies. Input cascode circuitry provides excellent common-mode rejection and maintains low input bias current over the wide input voltage range, minimizing distortion. The OPAx134 series operational amplifiers are unity-gain stable and provide excellent dynamic behavior over a wide range of load conditions, including high load capacitance. The dual and quad versions feature completely independent circuitry for lowest crosstalk and freedom from interaction, even when overdriven or overloaded.

Single and dual versions are available in 8-pin DIP and SO-8 surface-mount packages in standard configurations. The quad is available in SO-14 surface-mount package. All are specified for  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$  operation. A SPICE macromodel is available for design analysis.

### Device Information

| PART NUMBER | CHANNEL COUNT | PACKAGE <sup>(1)</sup> |
|-------------|---------------|------------------------|
| OPA134      | Single        | D (SOIC, 8)            |
|             |               | P (PDIP, 8)            |
| OPA2134     | Dual          | D (SOIC, 8)            |
|             |               | P (PDIP, 8)            |
| OPA4134     | Quad          | D (SOIC, 14)           |

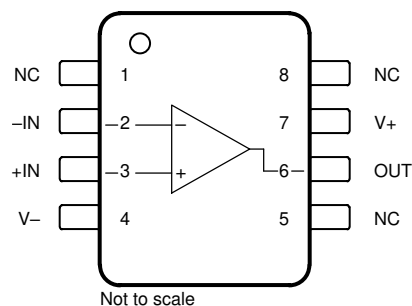
(1) For more information, see also [Section 10](#).



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## 4 Pin Configuration and Functions

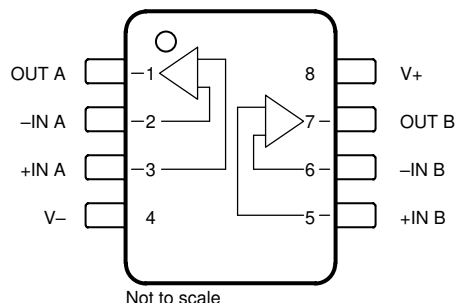


**Figure 4-1. OPA134: D Package, 8-Pin SOIC, and P Package, 8-Pin PDIP (Top View)**

**Pin Functions: OPA134**

| PIN    |      | TYPE   | DESCRIPTION                              |
|--------|------|--------|------------------------------------------|
| NAME   | NO.  |        |                                          |
| +IN    | 3    | Input  | Noninverting input                       |
| –IN    | 2    | Input  | Inverting input                          |
| NC     | 1, 5 | —      | Do not connect these pins <sup>(1)</sup> |
| NC     | 8    | —      | No internal connection. Float this pin.  |
| Output | 6    | Output | Output                                   |
| V+     | 7    | Power  | Positive power supply                    |
| V–     | 4    | Power  | Negative power supply                    |

(1) Existing layouts for the OPA134 before revision B of this data sheet do not need to be redesigned.



**Figure 4-2. OPA2134: D Package, 8-Pin SOIC, and P Package, 8-Pin PDIP (Top View)**

**Table 4-1. Pin Functions: OPA2134**

| PIN   |     | TYPE   | DESCRIPTION                     |
|-------|-----|--------|---------------------------------|
| NAME  | NO. |        |                                 |
| +IN A | 3   | Input  | Noninverting input, channel A   |
| +IN B | 5   | Input  | Noninverting input, channel B   |
| –IN A | 2   | Input  | Inverting input, channel A      |
| –IN B | 6   | Input  | Inverting input, channel B      |
| OUT A | 1   | Output | Output, channel A               |
| OUT B | 7   | Output | Output, channel B               |
| V+    | 8   | Power  | Positive (highest) power supply |
| V–    | 4   | Power  | Negative (lowest) power supply  |

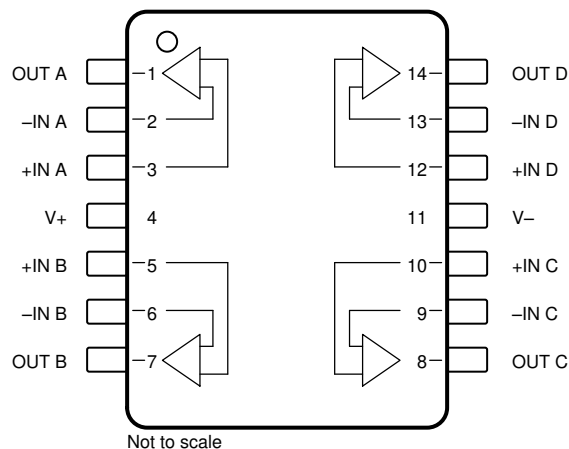


Figure 4-3. OPA4134: D Package, 14-Pin SOIC (Top View)

Table 4-2. Pin Functions: OPA4134

| PIN   |     | TYPE   | DESCRIPTION                     |
|-------|-----|--------|---------------------------------|
| NAME  | NO. |        |                                 |
| +IN A | 3   | Input  | Noninverting input, channel A   |
| +IN B | 5   | Input  | Noninverting input, channel B   |
| +IN C | 10  | Input  | Noninverting input, channel C   |
| +IN D | 12  | Input  | Noninverting input, channel D   |
| –IN A | 2   | Input  | Inverting input, channel A      |
| –IN B | 6   | Input  | Inverting input, channel B      |
| –IN C | 9   | Input  | Inverting input, channel C      |
| –IN D | 13  | Input  | Inverting input, channel D      |
| OUT A | 1   | Output | Output, channel A               |
| OUT B | 7   | Output | Output, channel B               |
| OUT C | 8   | Output | Output, channel C               |
| OUT D | 14  | Output | Output, channel D               |
| V+    | 4   | Power  | Positive (highest) power supply |
| V–    | 11  | Power  | Negative (lowest) power supply  |

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

|                  |                                     |               | MIN        | MAX        | UNIT |
|------------------|-------------------------------------|---------------|------------|------------|------|
| V <sub>S</sub>   | Supply voltage, (V+) – (V–)         | Single supply |            | 36         | V    |
|                  | Input voltage <sup>(2)</sup>        |               | (V–) – 0.5 | (V+) + 0.5 | V    |
|                  | Input current <sup>(2)</sup>        |               |            | ±10        | mA   |
| I <sub>SC</sub>  | Output short-circuit <sup>(3)</sup> |               | Continuous |            |      |
| T <sub>A</sub>   | Operating temperature               |               | –40        | 125        | °C   |
| T <sub>J</sub>   | Junction temperature                |               |            | 150        | °C   |
| T <sub>stg</sub> | Storage temperature                 |               | –55        | 125        | °C   |

- (1) Operation outside the *Absolute Maximum Ratings* may cause permanent device damage. *Absolute Maximum Ratings* do not imply functional operation of the device at these or any other conditions beyond those listed under *Recommended Operating Conditions*. If used outside the *Recommended Operating Conditions* but within the *Absolute Maximum Ratings*, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails must be current limited to 10mA or less.
- (3) Short-circuit to ground, one amplifier per package.

### 5.2 ESD Ratings

|                                                               |                         |                                                                                | VALUE | UNIT |
|---------------------------------------------------------------|-------------------------|--------------------------------------------------------------------------------|-------|------|
| OPA134 in SOIC and PDIP Packages, and OPA2134 in PDIP Package |                         |                                                                                |       |      |
| V <sub>(ESD)</sub>                                            | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
| OPA2134 in SOIC Package                                       |                         |                                                                                |       |      |
| V <sub>(ESD)</sub>                                            | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                                                               |                         | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |      |
| OPA4134 in SOIC Package                                       |                         |                                                                                |       |      |
| V <sub>(ESD)</sub>                                            | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 | V    |
|                                                               | Electrostatic discharge | Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±200  |      |

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

|                |                             |               | MIN  | NOM | MAX | UNIT |
|----------------|-----------------------------|---------------|------|-----|-----|------|
| V <sub>S</sub> | Supply voltage, (V+) – (V–) | Dual supply   | ±2.5 | ±15 | ±18 | V    |
|                |                             | Single supply | 5    | 30  | 36  |      |
| T <sub>A</sub> | Ambient temperature         |               | –40  |     | +85 | °C   |

## 5.4 Thermal Information - OPA134

| THERMAL METRIC <sup>(1)</sup> |                                              | OPA134   |          | UNIT |
|-------------------------------|----------------------------------------------|----------|----------|------|
|                               |                                              | D (SOIC) | P (PDIP) |      |
|                               |                                              | 8 PINS   | 8 PINS   |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 160      | 73       | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 75       | 50       | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 60       | 36       | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 9        | 17       | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 50       | 35       | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A      | N/A      | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 5.5 Thermal Information - OPA2134

| THERMAL METRIC <sup>(1)</sup> |                                              | OPA2134  |          | UNIT |
|-------------------------------|----------------------------------------------|----------|----------|------|
|                               |                                              | D (SOIC) | P (PDIP) |      |
|                               |                                              | 8 PINS   | 8 PINS   |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 160      | 71       | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 75       | 50       | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 60       | 36       | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 9        | 16       | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 50       | 35       | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A      | N/A      | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 5.6 Thermal Information - OPA4134

| THERMAL METRIC <sup>(1)</sup> |                                              | OPA4132  | UNIT |
|-------------------------------|----------------------------------------------|----------|------|
|                               |                                              | D (SOIC) |      |
|                               |                                              | 14 PINS  |      |
| $R_{\theta JA}$               | Junction-to-ambient thermal resistance       | 97       | °C/W |
| $R_{\theta JC(top)}$          | Junction-to-case (top) thermal resistance    | 56       | °C/W |
| $R_{\theta JB}$               | Junction-to-board thermal resistance         | 53       | °C/W |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 19       | °C/W |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 46       | °C/W |
| $R_{\theta JC(bot)}$          | Junction-to-case (bottom) thermal resistance | N/A      | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 5.7 Electrical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)

| PARAMETER            |                                      | TEST CONDITIONS                                         |                       | MIN                             | TYP  | MAX        | UNIT              |
|----------------------|--------------------------------------|---------------------------------------------------------|-----------------------|---------------------------------|------|------------|-------------------|
| AUDIO PERFORMANCE    |                                      |                                                         |                       |                                 |      |            |                   |
| THD+N                | Total harmonic distortion plus noise | f = 1kHz, G = 1, V <sub>O</sub> = 3V <sub>rms</sub>     | R <sub>L</sub> = 2kΩ  | 0.00008                         |      |            | %                 |
|                      |                                      |                                                         | R <sub>L</sub> = 600Ω | 0.00015                         |      |            |                   |
|                      | Intermodulation distortion           | f = 1kHz, G = 1, V <sub>O</sub> = 1V <sub>pp</sub>      |                       | −98                             |      |            | dB                |
|                      | Headroom <sup>(1)</sup>              | THD < 0.01%, R <sub>L</sub> = 2kΩ, V <sub>S</sub> = 18V |                       | 21.3                            |      |            | dBu               |
| FREQUENCY RESPONSE   |                                      |                                                         |                       |                                 |      |            |                   |
| GBW                  | Gain bandwidth product               |                                                         |                       | 8                               |      |            | MHz               |
| SR                   | Slew rate <sup>(2)</sup>             |                                                         |                       | ±20                             |      |            | V/μs              |
|                      | Settling time                        | 10V step, G = 1, C <sub>L</sub> = 100pF                 | 0.1%                  | 0.7                             |      |            | μs                |
|                      |                                      |                                                         | 0.01%                 | 1                               |      |            |                   |
| FPBW                 | Full power bandwidth                 |                                                         |                       | 1.3                             |      |            | MHz               |
|                      | Overload recovery time               | V <sub>IN</sub> × G = V <sub>S</sub>                    |                       | 0.6                             |      |            | μs                |
| NOISE                |                                      |                                                         |                       |                                 |      |            |                   |
|                      | Input voltage noise                  | f = 20Hz to 20kHz                                       |                       | 1.2                             |      |            | μV <sub>rms</sub> |
| e <sub>n</sub>       | Input voltage noise density          | f = 1kHz                                                |                       | 8                               |      |            | nV/√Hz            |
| i <sub>n</sub>       | Input current noise density          | f = 1kHz                                                |                       | 3                               |      |            | fA/√Hz            |
| OFFSET VOLTAGE       |                                      |                                                         |                       |                                 |      |            |                   |
| V <sub>OS</sub>      | Input offset voltage                 |                                                         |                       | ±1                              | ±3.5 |            | mV                |
|                      |                                      | T <sub>A</sub> = −40°C to +85°C                         |                       | ±1                              |      |            |                   |
| dV <sub>OS</sub> /dT | Input offset voltage drift           | T <sub>A</sub> = −40°C to +85°C                         |                       | ±2                              |      |            | μV/°C             |
| PSRR                 | Power-supply rejection ratio         | 5V ≤ V <sub>S</sub> ≤ 36V                               |                       | 90                              | 106  |            | dB                |
|                      | Channel separation (dual, quad)      | DC, R <sub>L</sub> = 2kΩ                                |                       | 128                             |      |            | dB                |
|                      |                                      | f = 20kHz, R <sub>L</sub> = 2kΩ                         |                       | 126                             |      |            |                   |
| INPUT BIAS CURRENT   |                                      |                                                         |                       |                                 |      |            |                   |
| I <sub>B</sub>       | Input bias current <sup>(3)</sup>    |                                                         |                       | ±5                              | ±100 |            | pA                |
|                      |                                      | T <sub>A</sub> = −40°C to +85°C                         |                       | See <a href="#">Section 5.8</a> |      | ±5         | nA                |
| I <sub>OS</sub>      | Input offset current <sup>(3)</sup>  |                                                         |                       | ±2                              | ±50  |            | pA                |
| INPUT VOLTAGE        |                                      |                                                         |                       |                                 |      |            |                   |
| V <sub>CM</sub>      | Common-mode voltage                  |                                                         |                       | (V−) + 2.5                      | ±13  | (V+) − 3.5 | V                 |
| CMRR                 | Common-mode rejection ratio          | −12.5V ≤ V <sub>CM</sub> ≤ 11.5V                        |                       | 86                              | 100  |            | dB                |
|                      |                                      |                                                         | TA = −40°C to +85°C   | 90                              |      |            |                   |
| INPUT IMPEDANCE      |                                      |                                                         |                       |                                 |      |            |                   |
|                      | Differential                         |                                                         |                       | 10 <sup>13</sup>    8           |      |            | Ω    pF           |
|                      | Common-mode                          | −12.5V ≤ V <sub>CM</sub> ≤ 11.5V                        |                       | 10 <sup>13</sup>    6           |      |            | Ω    pF           |
| OPEN-LOOP GAIN       |                                      |                                                         |                       |                                 |      |            |                   |
| A <sub>OL</sub>      | Open-loop voltage gain               | R <sub>L</sub> = 10kΩ, −14.5V ≤ V <sub>O</sub> ≤ 13.8V  |                       | 104                             | 120  |            | dB                |
|                      |                                      | R <sub>L</sub> = 2kΩ, −13.8V ≤ V <sub>O</sub> ≤ 13.5V   |                       | 104                             | 120  |            |                   |

## 5.7 Electrical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)

| PARAMETER       |                                   | TEST CONDITIONS       |                            | MIN                                | TYP | MAX | UNIT |    |
|-----------------|-----------------------------------|-----------------------|----------------------------|------------------------------------|-----|-----|------|----|
| OUTPUT          |                                   |                       |                            |                                    |     |     |      |    |
| V <sub>O</sub>  | Voltage output                    | R <sub>L</sub> = 10kΩ | Positive                   | (V+) – 1.2                         |     |     | V    |    |
|                 |                                   |                       | Negative                   | (V–) + 0.5                         |     |     |      |    |
|                 |                                   | R <sub>L</sub> = 2kΩ  | Positive                   | (V+) – 1.5                         |     |     |      |    |
|                 |                                   |                       | Negative                   | (V–) + 1.2                         |     |     |      |    |
| I <sub>sc</sub> | Short-circuit current             | Sourcing              |                            | 36                                 |     |     | mA   |    |
|                 |                                   | Sinking               |                            | –30                                |     |     |      |    |
| Z <sub>O</sub>  | Output impedance                  | f = 10kHz             | Closed-loop <sup>(4)</sup> | 0.01                               |     |     | Ω    |    |
|                 |                                   |                       | Open-loop                  | 10                                 |     |     |      |    |
|                 | Capacitive load drive             | Stable operation      |                            | See <i>Typical Characteristics</i> |     |     |      |    |
| POWER SUPPLY    |                                   |                       |                            |                                    |     |     |      |    |
| I <sub>Q</sub>  | Quiescent current (per amplifier) | I <sub>O</sub> = 0mA  |                            | 4                                  |     |     | 5    | mA |

- (1)  $\text{dBu} = 20 \times \log (V_{\text{rms}} / 0.7746)$  where  $V_{\text{rms}}$  is the maximum output voltage for which THD+Noise is less than 0.01%. See *Total Harmonic Distortion*.
- (2) Proposed by design.
- (3) High-speed test at  $T_J = 25^\circ\text{C}$ .
- (4) See *Closed-Loop Output Impedance vs Frequency* in *Typical Characteristics*.



## 5.8 Typical Characteristics

at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)

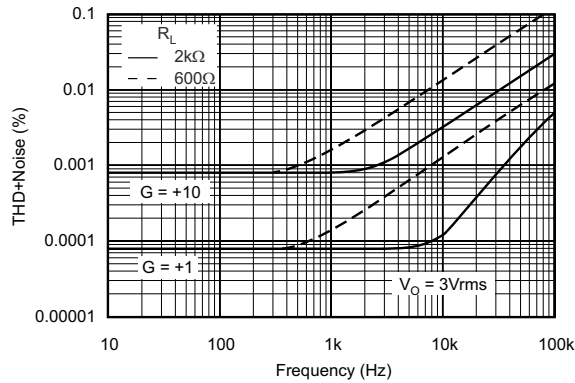


Figure 5-1. Total Harmonic Distortion + Noise vs Frequency

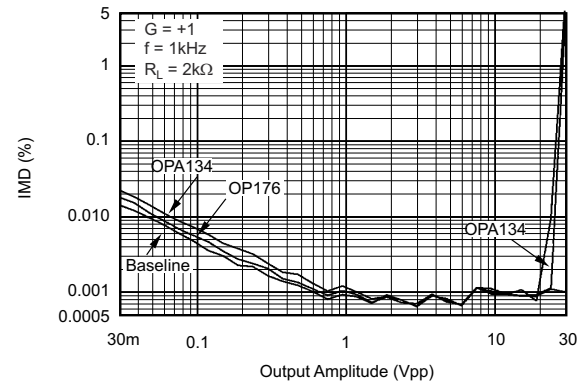


Figure 5-2. SMPTE Intermodulation Distortion vs Output Amplitude

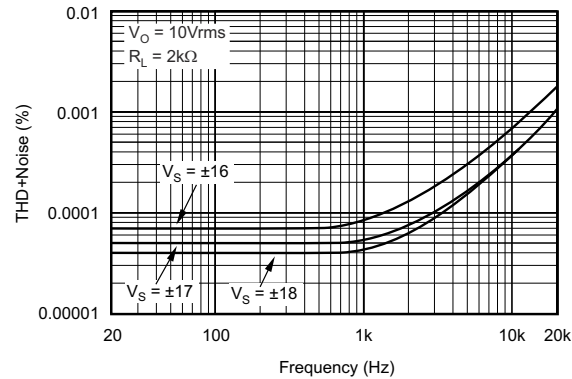


Figure 5-3. Total Harmonic Distortion + Noise vs Frequency

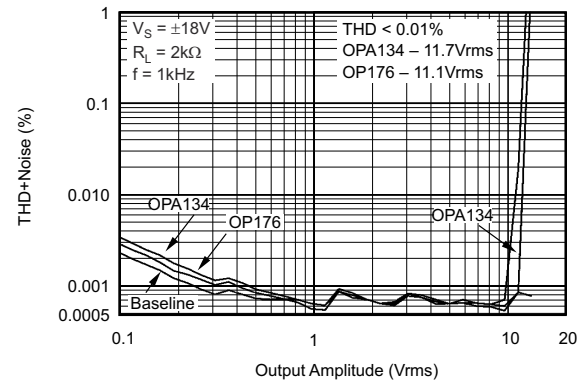


Figure 5-4. Headroom – Total Harmonic Distortion + Noise vs Output Amplitude

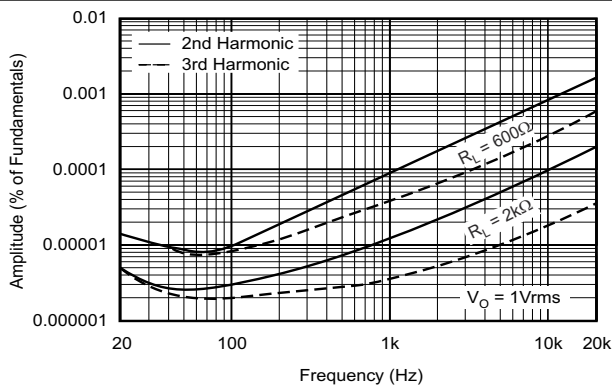


Figure 5-5. Harmonic Distortion + Noise vs Frequency

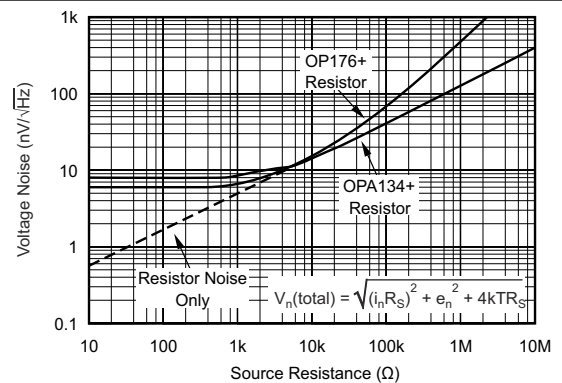
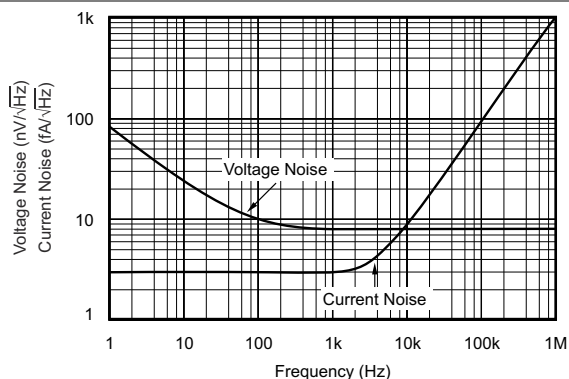


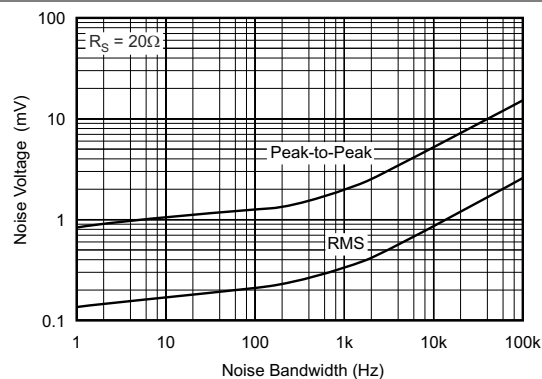
Figure 5-6. Voltage Noise vs Source Resistance

## 5.8 Typical Characteristics (continued)

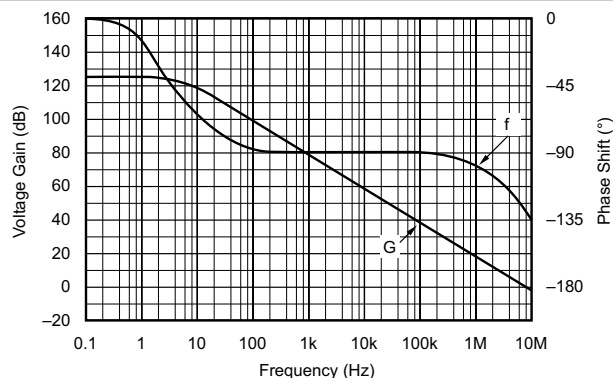
at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)



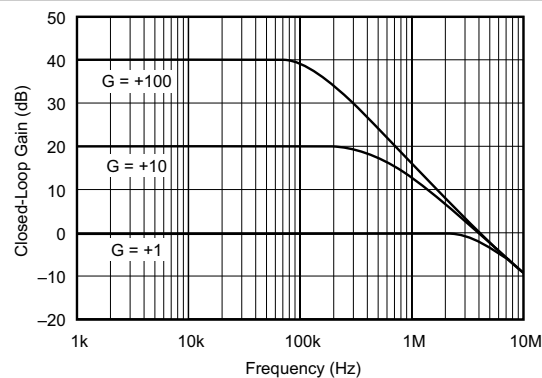
**Figure 5-7. Input Voltage and Current Noise Spectral Density vs Frequency**



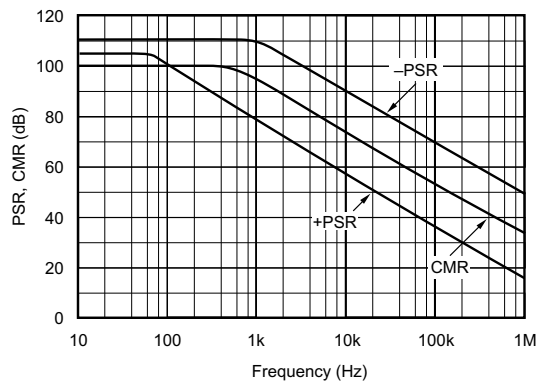
**Figure 5-8. Input-Referred Noise Voltage vs Noise Bandwidth**



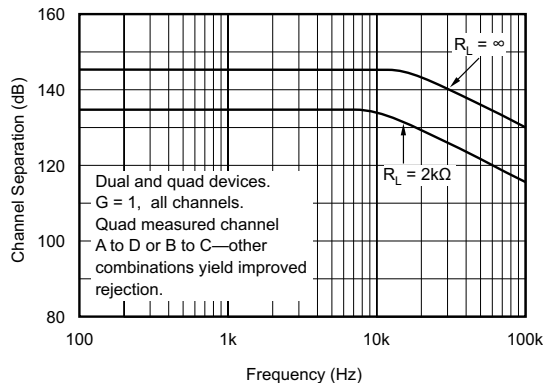
**Figure 5-9. Open-Loop Gain and Phase vs Frequency**



**Figure 5-10. Closed-Loop Gain vs Frequency**



**Figure 5-11. Power Supply and Common-Mode Rejection vs Frequency**



**Figure 5-12. Channel Separation vs Frequency**

## 5.8 Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)

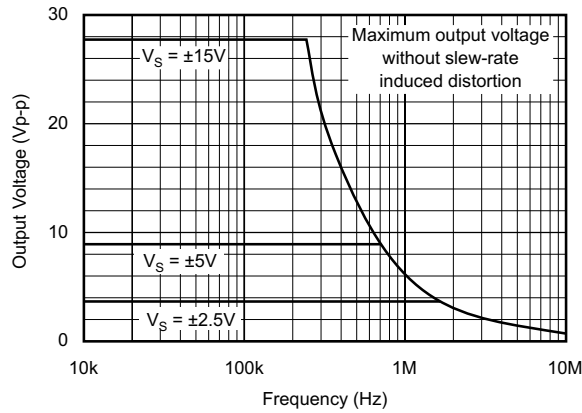


Figure 5-13. Maximum Output Voltage vs Frequency

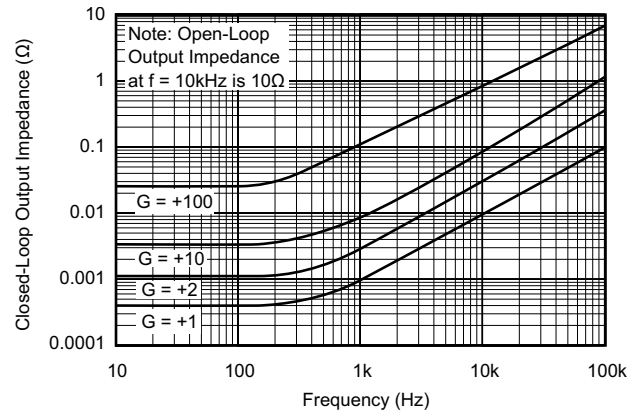


Figure 5-14. Closed-Loop Output Impedance vs Frequency

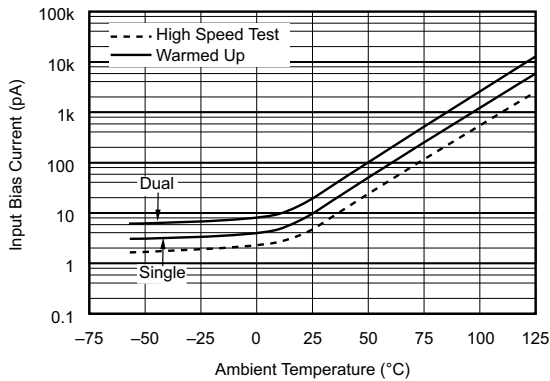


Figure 5-15. Input Bias Current vs Temperature

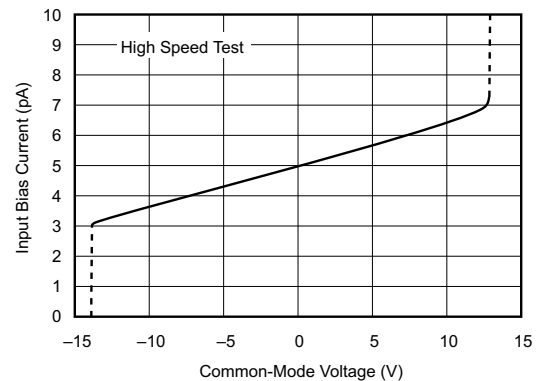


Figure 5-16. Input Bias Current vs Input Common-Mode Voltage

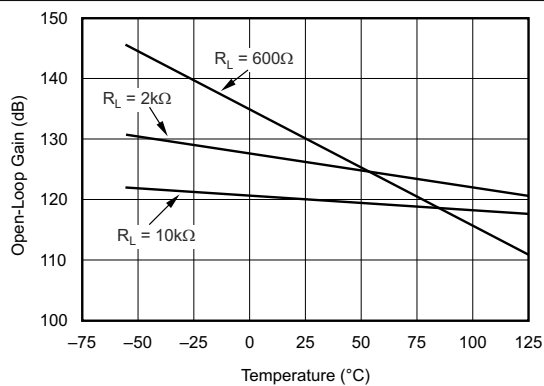


Figure 5-17. Open-Loop Gain vs Temperature

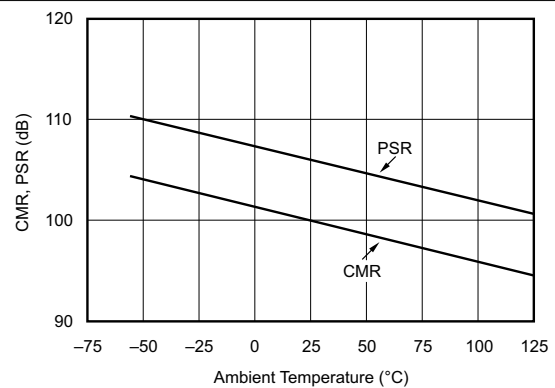
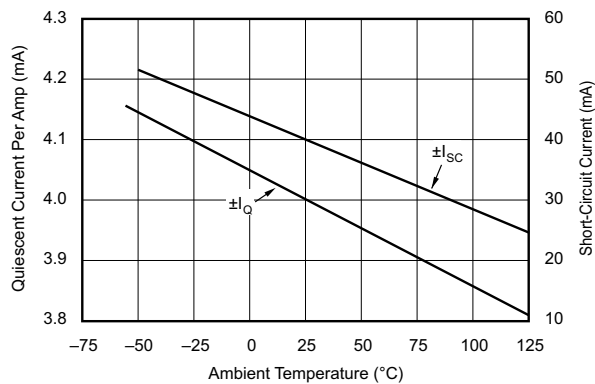


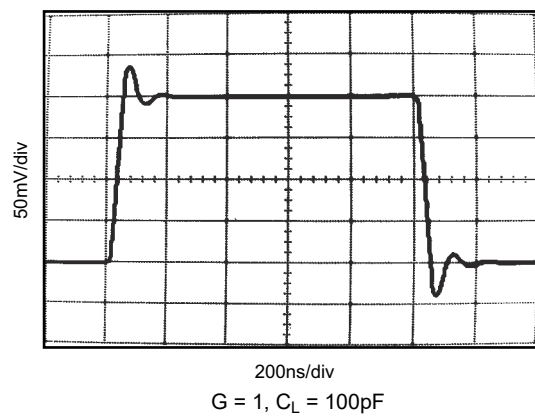
Figure 5-18. CMR, PSR vs Temperature

## 5.8 Typical Characteristics (continued)

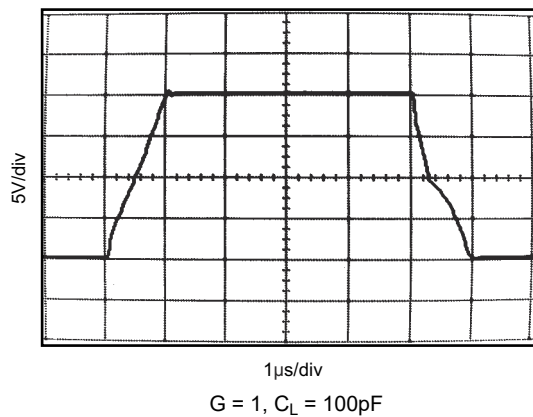
at  $T_A = 25^\circ\text{C}$ ,  $V_S = \pm 15\text{V}$ ,  $R_L = 2\text{k}\Omega$  connected to midsupply, and  $V_{CM} = V_{OUT} = \text{midsupply}$  (unless otherwise noted)



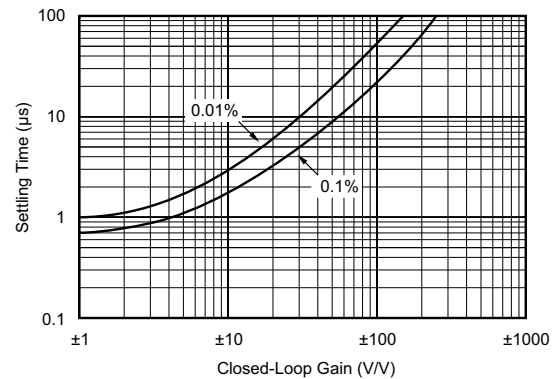
**Figure 5-19. Quiescent Current and Short-Circuit Current vs Temperature**



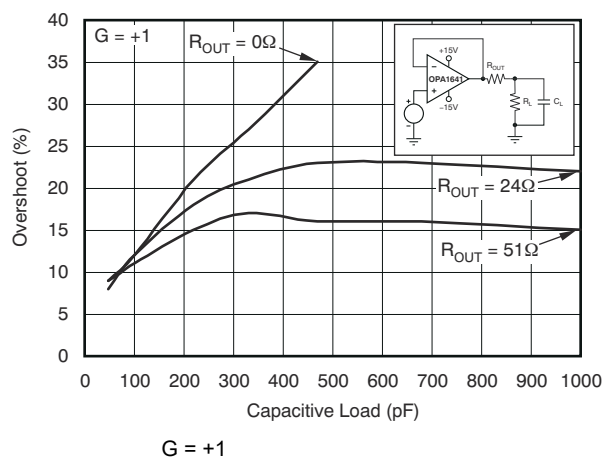
**Figure 5-20. Small-Signal Step Response**



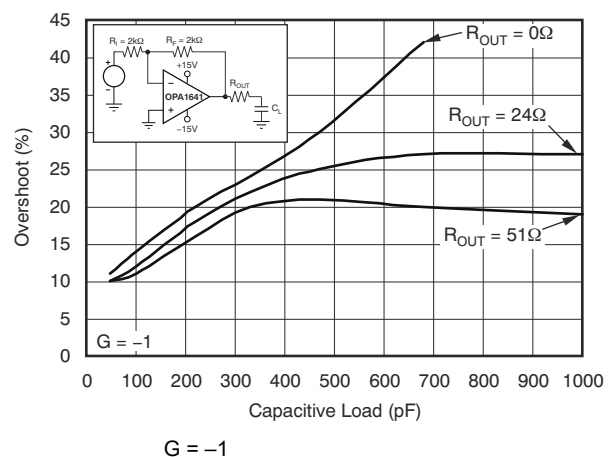
**Figure 5-21. Large-Signal Step Response**



**Figure 5-22. Settling Time vs Closed-Loop Gain**



**Figure 5-23. Small-Signal Overshoot vs Load Capacitance**



**Figure 5-24. Small-Signal Overshoot vs Load Capacitance**

## 6 Detailed Description

### 6.1 Overview

The OPA134 series are ultra-low distortion, low-noise operational amplifiers fully specified for audio applications. A true FET input stage is incorporated to provide unmatched sound quality and speed for exceptional audio performance. This, in combination with high output drive capability and excellent DC performance, allows for use in a wide variety of demanding applications. In addition, the OPA134 has a wide output swing, to within 1V of the rails, allowing increased headroom and making this op amp an excellent choice for any audio circuit.

### 6.2 Feature Description

#### 6.2.1 Total Harmonic Distortion

The OPAx134 series of operational amplifiers have excellent distortion characteristics. THD+Noise is below 0.0004% throughout the audio frequency range, 20Hz to 20kHz, with a 2k $\Omega$  load. In addition, distortion remains relatively flat through the wide output voltage swing range, providing increased headroom compared to other audio amplifiers, including the OP176/275.

Headroom is a subjective measurement, and can be thought of as the maximum output amplitude allowed while still maintaining a low level of distortion. In an attempt to quantify headroom, TI defines very low distortion as 0.01%. Headroom is expressed as a ratio which compares the maximum allowable output voltage level to a standard output level (1mW into 600 $\Omega$ , or 0.7746Vrms). Therefore, OPA134 series of operational amplifiers, which have a maximum allowable output voltage level of 11.7Vrms (THD+Noise < 0.01%), have a headroom specification of 23.6dBu. See [Figure 5-4](#).

## 6.2.2 Distortion Measurements

The distortion produced by OPAx134 series of operational amplifiers is below the measurement limit of all known commercially-available equipment. However, a special test circuit can extend the measurement capabilities.

Operational amplifier distortion can be considered an internal error source which can be referred to the input. Figure 6-1 shows a circuit which causes the operational amplifier distortion to be 101 times greater than that which the operational amplifier normally produces. The addition of  $R_3$  to the otherwise standard non-inverting amplifier configuration alters the feedback factor or noise gain of the circuit. The closed-loop gain is unchanged, but the feedback available for error correction is reduced by a factor of 101, thus extending the resolution by 101. The input signal and load applied to the operational amplifier are the same as with conventional feedback without  $R_3$ . Keep the value of  $R_3$  small to minimize effect on the distortion measurements.

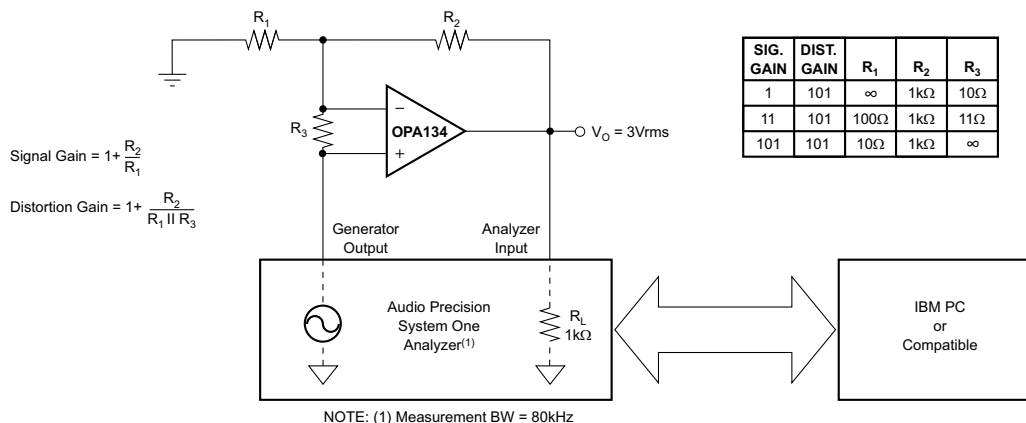


Figure 6-1. Distortion Test Circuit

This technique can be verified by duplicating measurements at high gain or high frequency, where the distortion is within the measurement capability of the test equipment. Measurements for this data sheet were made with an Audio Precision distortion and noise analyzer, which greatly simplifies repetitive measurements. The measurement technique can, however, be performed with manual distortion measurement instruments.

## 6.2.3 Source Impedance and Distortion

For lowest distortion with a source or feedback network with an impedance greater than 2k $\Omega$ , match the impedance seen by the positive and negative inputs in noninverting applications. The p-channel JFETs in the FET input stage exhibit a varying input capacitance with applied common-mode input voltage. In inverting configurations, the input does not vary with input voltage, because the inverting input is held at virtual ground. However, in noninverting applications the inputs do vary, and the gate-to-source voltage is not constant. The effect is increased distortion due to the varying capacitance for unmatched source impedances greater than 2k $\Omega$ .

To maintain low distortion, match unbalanced source impedance with the appropriate values in the feedback network as shown in Figure 6-2. Of course, the unbalanced impedance can be from gain-setting resistors in the feedback path. If the parallel combination of  $R_1$  and  $R_2$  is greater than 2k $\Omega$ , use a matching impedance on the noninverting input. As always, minimize resistor values to reduce the effects of thermal noise.

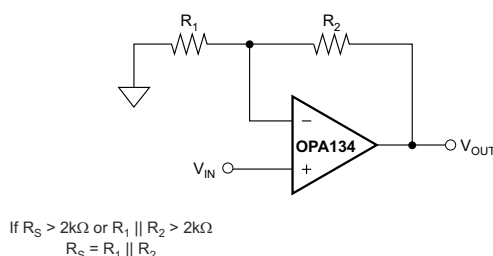


Figure 6-2. Impedance Matching for Maintaining Low Distortion in Noninverting Circuits

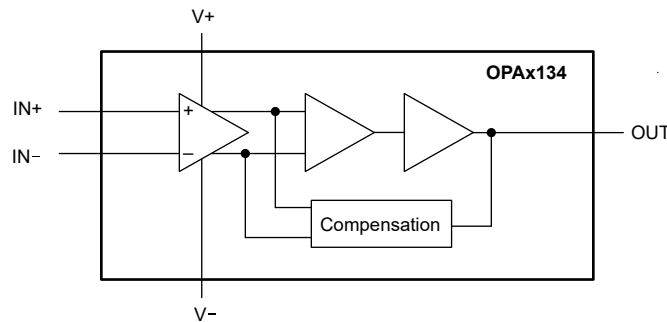
### 6.2.4 Phase Reversal Protection

The OPAx134 series of operational amplifiers are free from output phase-reversal problems. Many audio operational amplifiers, such as the OP176, exhibit phase-reversal of the output when the input common-mode voltage range is exceeded. This can occur in voltage-follower circuits, causing serious problems in control loop applications. The OPA134 series operational amplifiers are free from this undesirable behavior even with inputs of 10V beyond the input common-mode range.

### 6.2.5 Output Current Limit

Output current is limited by internal circuitry to approximately sourcing 36mA and sinking –30mA at 25°C. The limit current decreases with increasing temperature, as shown in [Figure 5-19](#).

## 6.3 Functional Block Diagram



## 6.4 Device Functional Modes

### 6.4.1 Noise Performance

Circuit noise is determined by the thermal noise of external resistors and operational amplifier noise. Operational amplifier noise is described by two parameters: noise voltage and noise current. The total noise is quantified by the equation:

$$V_n(\text{total}) = \sqrt{e_n^2 + (i_n R_S)^2 + 4kTR_S} \quad (1)$$

With low source impedance, the current noise term is insignificant and voltage noise dominates the noise performance. At high source impedance, the current noise term becomes the dominant contributor.

Low-noise bipolar operational amplifiers such as the OPA27 and OPA37 provide low voltage noise at the expense of a higher current noise. However, OPAx134 series operational amplifiers provide both low voltage noise and low current noise. This provides optimum noise performance over a wide range of sources, including reactive source impedances; refer to [Figure 5-6](#). Above 2kΩ source resistance, the operational amplifier contributes little additional noise; the voltage and current terms in the total noise equation become insignificant and the source resistance term dominates. Below 2kΩ, operational amplifier voltage noise dominates over the resistor noise, but compares favorably with other audio operational amplifiers such as the OP176.

## 7 Application and Implementation

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### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

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### 7.1 Application Information

The OPAx134 series operational amplifiers are unity-gain stable, and an excellent choice for a wide range of audio and general-purpose applications. All circuitry is independent in the dual version, maintaining normal behavior when one amplifier in a package is overdriven or short-circuited. Bypass the power supply pins with 10nF ceramic capacitors or larger to minimize power supply noise.

#### 7.1.1 Operating Voltage

The OPAx134 series of operational amplifiers operate with power supplies from  $\pm 2.5\text{V}$  to  $\pm 18\text{V}$  with excellent performance. Although specifications are production tested with  $\pm 15\text{V}$  supplies, most behavior remains unchanged throughout the full operating voltage range. Parameters which vary significantly with operating voltage are shown in [Section 5.8](#).

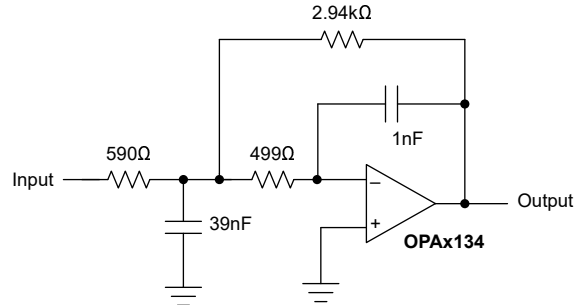
#### 7.1.2 Offset Voltage Trim

Offset voltage of OPAx134 series amplifiers are laser-trimmed, and usually require no user adjustment. The OPAx134 provide less than  $\pm 2\text{mV}$  of input offset voltage and a typical input offset voltage drift of  $10\mu\text{V}/^\circ\text{C}$  over the operating temperature range.



## 7.2 Typical Application

The OPAx134 family offers outstanding dc precision and AC performance. These devices operate up to 36V supply rails and offer ultra-low distortion and noise, as well as 8MHz bandwidth and high capacitive load drive. These features make the OPAx134 a robust, high-performance operational amplifier for high-voltage professional audio applications.



**Figure 7-1. OPA134 2nd-Order, 30kHz, Low-Pass Filter Schematic**

### 7.2.1 Design Requirements

- Gain = 5V/V (inverting)
- Low-pass cutoff frequency = 30kHz
- –40db/dec filter response
- Maintain less than 3dB gain peaking in the gain versus frequency response

### 7.2.2 Detailed Design Procedure

The infinite-gain multiple-feedback circuit for a low-pass network function is shown in [Figure 7-1](#). The voltage transfer function is:

$$\frac{Output}{Input}(s) = \frac{\frac{-1}{R_1 R_3 C_2 C_5}}{s^2 + s \left( \frac{1}{C_2} \right) \left( \frac{1}{R_1} + \frac{1}{R_3} + \frac{1}{R_4} \right) + \left( \frac{1}{R_3 R_4 C_2 C_5} \right)} \quad (2)$$

This circuit produces a signal inversion. For this circuit, the gain at DC and the low-pass cutoff frequency are calculated using [Equation 3](#) and [Equation 4](#).

$$Gain = \frac{R_4}{R_1} \quad (3)$$

$$f_c = \frac{1}{2\pi} \sqrt{\frac{1}{R_3 R_4 C_2 C_5}} \quad (4)$$

**WEBENCH® Circuit Designer** creates customized power supply and active filter circuits based on your system requirements. The environment gives you end-to-end selection, design, and simulation capabilities that save you time during all phases of the analog design process.

Use our tools to help with your designs:

- [Filter design tool](#)
- [Powerstage designer](#)
- [WEBENCH® Power designer](#)
- [PCB thermal calculator](#)

### 7.2.3 Application Curve

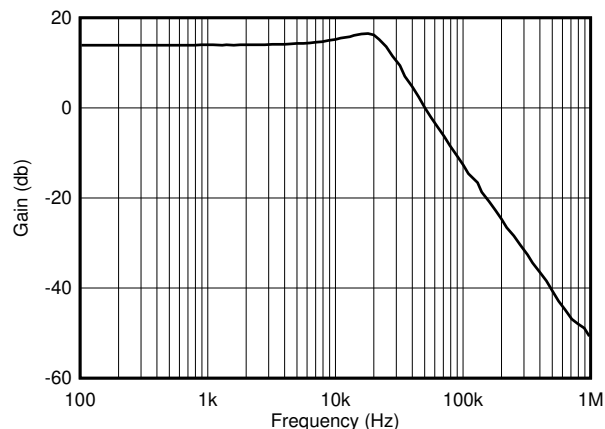


Figure 7-2. OPA134 2nd-Order, 30kHz, Low-Pass Filter Response

### 7.3 Power Supply Recommendations

The OPAx134 is specified for operation from 5V to 36V ( $\pm 2.5\text{V}$  to  $\pm 18\text{V}$ ); many specifications apply from  $-40^\circ\text{C}$  to  $+85^\circ\text{C}$ . Parameters that can exhibit significant variance with regard to operating voltage or temperature are presented in [Section 5.8](#).

#### CAUTION

Supply voltages larger than 36V can permanently damage the device; see [Section 5.1](#).

Place 10nF bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement, see [Section 7.4.1](#).

### 7.4 Layout

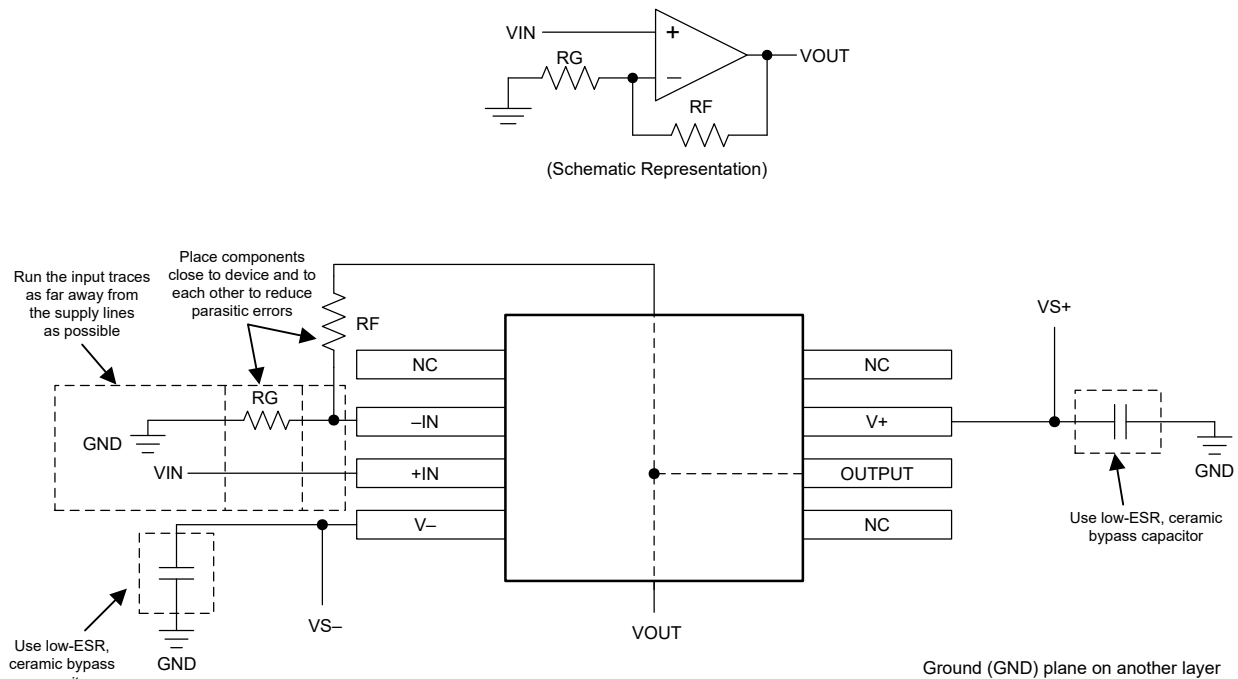
#### 7.4.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the operational amplifier and the power pins of the circuit as a whole. Bypass capacitors are used to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 10nF ceramic bypass capacitors between each supply pin and ground, placed as close as possible to the device. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Make sure to physically separate digital and analog grounds paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicular is much better as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. As shown in [Section 7.4.2](#), keeping RF and RG close to the inverting input minimizes parasitic capacitance.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.
- Cleaning the PCB following board assembly is recommended for best performance.

- Any precision integrated circuit can experience performance shifts due to moisture ingress into the plastic package. Following any aqueous PCB cleaning process, TI recommends baking the PCB assembly to remove moisture introduced into the device packaging during the cleaning process. A low temperature, post cleaning bake at 85°C for 30 minutes is sufficient for most circumstances.

### 7.4.2 Layout Example



**Figure 7-3. OPA134 Layout Example for the Noninverting Configuration**

## 8 Device and Documentation Support

### 8.1 Device Support

#### 8.1.1 Development Support

##### 8.1.1.1 Analog Filter Designer

Available as a web-based tool from the [Design and simulation tool](#) web page, the [Analog Filter Designer](#) allows the user to design, optimize, and simulate complete multistage active filter solutions within minutes.

##### 8.1.1.2 TINA-TI™ Simulation Software (Free Download)

TINA-TI™ simulation software is a simple, powerful, and easy-to-use circuit simulation program based on a SPICE engine. TINA-TI simulation software is a free, fully-functional version of the TINA™ software, preloaded with a library of macromodels, in addition to a range of both passive and active models. TINA-TI simulation software provides all the conventional dc, transient, and frequency domain analysis of SPICE, as well as additional design capabilities.

Available as a [free download](#) from the [Design and simulation tools](#) web page, TINA-TI simulation software offers extensive post-processing capability that allows users to format results in a variety of ways. Virtual instruments offer the ability to select input waveforms and probe circuit nodes, voltages, and waveforms, creating a dynamic quick-start tool.

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#### Note

These files require that either the TINA software or TINA-TI software be installed. Download the free TINA-TI simulation software from the [TINA-TI™ software folder](#).

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##### 8.1.1.3 TI Reference Designs

TI reference designs are analog solutions created by TI's precision analog applications experts. TI reference designs offer the theory of operation, component selection, simulation, complete PCB schematic and layout, bill of materials, and measured performance of many useful circuits. TI reference designs are available online at <https://www.ti.com/reference-designs>.

### 8.2 Documentation Support

#### 8.2.1 Related Documentation

For related documentation, see the following (available for download from [www.ti.com](http://www.ti.com)):

- Texas Instruments, [EMI Rejection Ratio of Operational Amplifiers](#)
- Texas Instruments, [Circuit Board Layout Techniques](#)

### 8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 8.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

### 8.5 Trademarks

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TINA™ is a trademark of DesignSoft, Inc.

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## 8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 8.7 Glossary

**TI Glossary** This glossary lists and explains terms, acronyms, and definitions.

## 9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Revision A (April 2015) to Revision B (August 2024)                                                                                                                                         | Page |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • Updated the numbering format for tables, figures, and cross-references throughout the document.....                                                                                                    | 1    |
| • Updated open-loop gain load condition in <i>Features</i> .....                                                                                                                                         | 1    |
| • Deleted PDIP package option for quad version device.....                                                                                                                                               | 1    |
| • Updated <i>Device Information</i> table.....                                                                                                                                                           | 1    |
| • Changed W to $\Omega$ symbol in front-page figure (typo) .....                                                                                                                                         | 1    |
| • Updated <i>Pin Configuration and Functions</i> format.....                                                                                                                                             | 3    |
| • Changed OPA134 pin 1 and 8 from "Offset Trim" to "NC".....                                                                                                                                             | 3    |
| • Changed input voltage from (V <sub>-</sub> ) – 0.7V to (V <sub>+</sub> ) + 0.7V to (V <sub>-</sub> ) – 0.5V to (V <sub>+</sub> ) + 0.5V in <i>Absolute Maximum Ratings</i> .....                       | 5    |
| • Added input current and related footnote to <i>Absolute Maximum Ratings</i> .....                                                                                                                      | 5    |
| • Added <i>Thermal Information</i> .....                                                                                                                                                                 | 6    |
| • Updated format of <i>Electrical Characteristics</i> .....                                                                                                                                              | 7    |
| • Updated nominal conditions in the header of <i>Electrical Characteristics</i> .....                                                                                                                    | 7    |
| • Changed headroom from 23.6dB to 21.3dB.....                                                                                                                                                            | 7    |
| • Deleted slew rate MIN.....                                                                                                                                                                             | 7    |
| • Changed overload recovery time from 0.5 $\mu$ s to 0.6 $\mu$ s.....                                                                                                                                    | 7    |
| • Changed input offset voltage MIN from $\pm 0.5$ mV to $\pm 1$ mV and MAX from $\pm 2$ mV to $\pm 3.5$ mV.....                                                                                          | 7    |
| • Deleted input offset voltage over temperature MAX.....                                                                                                                                                 | 7    |
| • Changed channel separation from 135dB to 128dB for dc, and from 130dB to 126dB for f = 20kHz .....                                                                                                     | 7    |
| • Deleted note 3.....                                                                                                                                                                                    | 7    |
| • Added $\pm$ to input bias current TYP.....                                                                                                                                                             | 7    |
| • Changed common-mode voltage MAX value from (V <sub>+</sub> ) – 2.5V to (V <sub>+</sub> ) – 3.5V.....                                                                                                   | 7    |
| • Updated common-mode rejection ratio and common-mode input impedance test conditions.....                                                                                                               | 7    |
| • Changed differential input impedance from $10^{13}\Omega \parallel 2$ pF to $10^{13}\Omega \parallel 8$ pF.....                                                                                        | 7    |
| • Changed common-mode input impedance from $10^{13}\Omega \parallel 5$ pF to $10^{13}\Omega \parallel 6$ pF.....                                                                                         | 7    |
| • Deleted open-loop voltage gain for R <sub>L</sub> = 600 $\Omega$ .....                                                                                                                                 | 7    |
| • Deleted voltage output for R <sub>L</sub> = 600 $\Omega$ .....                                                                                                                                         | 7    |
| • Moved voltage output negative MIN values to MAX values.....                                                                                                                                            | 7    |
| • Deleted output current.....                                                                                                                                                                            | 7    |
| • Deleted note 1 from <i>Electrical Characteristics</i> .....                                                                                                                                            | 7    |
| • Changed typos in typical characteristic graphs; corrected ohms symbol ( $\Omega$ ) and radical symbol ( $\sqrt{\phantom{x}}$ ).....                                                                    | 9    |
| • Changed test condition for <i>Typical Characteristics</i> from V <sub>S</sub> = 15V to V <sub>S</sub> = $\pm 15$ V (typo).....                                                                         | 9    |
| • Changed Figure 26, <i>Small-Signal Overshoot vs Load Capacitance</i> into new Figures 5-23 and 5-24.....                                                                                               | 9    |
| • Deleted old Figure 20, <i>Output Voltage Swing vs Output Current</i> , Figure 21, <i>Offset Voltage Production Distribution</i> , Figure 22, <i>Offset Voltage Drift Production Distribution</i> ..... | 9    |
| • Updated <i>Functional Block Diagram</i> .....                                                                                                                                                          | 15   |
| • Updated <i>Offset Voltage Trim</i> .....                                                                                                                                                               | 16   |
| • Updated <i>OPA134 Layout Example for the Noninverting Configuration</i> .....                                                                                                                          | 19   |

**Changes from Revision \* (September 2000) to Revision A (April 2015)****Page**

- Added *ESD Ratings* table, *Feature Description* section, *Device Functional Modes*, *Application and Implementation* section, *Power Supply Recommendations* section, *Layout* section, *Device and Documentation Support* section, and *Mechanical, Packaging, and Orderable Information* section..... 1

## 10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">OPA134PA</a>      | Active        | Production           | PDIP (P)   8   | 50   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -            | OPA134PA            |
| OPA134PA.A                    | Active        | Production           | PDIP (P)   8   | 50   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | OPA134PA            |
| <a href="#">OPA134UA</a>      | Active        | Production           | SOIC (D)   8   | 75   TUBE             | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>134UA        |
| OPA134UA.B                    | Active        | Production           | SOIC (D)   8   | 75   TUBE             | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>134UA        |
| <a href="#">OPA134UA/2K5</a>  | Active        | Production           | SOIC (D)   8   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>134UA        |
| OPA134UA/2K5.B                | Active        | Production           | SOIC (D)   8   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>134UA        |
| <a href="#">OPA2134PA</a>     | Active        | Production           | PDIP (P)   8   | 50   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | OPA2134PA           |
| OPA2134PA.A                   | Active        | Production           | PDIP (P)   8   | 50   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | OPA2134PA           |
| OPA2134PAG4                   | Active        | Production           | PDIP (P)   8   | 50   TUBE             | Yes         | NIPDAU                               | N/A for Pkg Type                  | -40 to 85    | OPA2134PA           |
| <a href="#">OPA2134UA</a>     | Active        | Production           | SOIC (D)   8   | 75   TUBE             | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>2134UA       |
| OPA2134UA.B                   | Active        | Production           | SOIC (D)   8   | 75   TUBE             | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>2134UA       |
| <a href="#">OPA2134UA/2K5</a> | Active        | Production           | SOIC (D)   8   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>2134UA       |
| OPA2134UA/2K5.B               | Active        | Production           | SOIC (D)   8   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>2134UA       |
| <a href="#">OPA4134UA</a>     | Active        | Production           | SOIC (D)   14  | 50   TUBE             | Yes         | NIPDAU   NIPDAU                      | Level-3-260C-168 HR               | -40 to 85    | OPA4134UA           |
| OPA4134UA.B                   | Active        | Production           | SOIC (D)   14  | 50   TUBE             | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA4134UA           |
| <a href="#">OPA4134UA/2K5</a> | Active        | Production           | SOIC (D)   14  | 2500   LARGE T&R      | Yes         | NIPDAU   NIPDAU                      | Level-3-260C-168 HR               | -40 to 85    | OPA4134UA           |
| OPA4134UA/2K5.B               | Active        | Production           | SOIC (D)   14  | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA4134UA           |
| SN412008DRE4                  | Active        | Production           | SOIC (D)   8   | 2500   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 85    | OPA<br>2134UA       |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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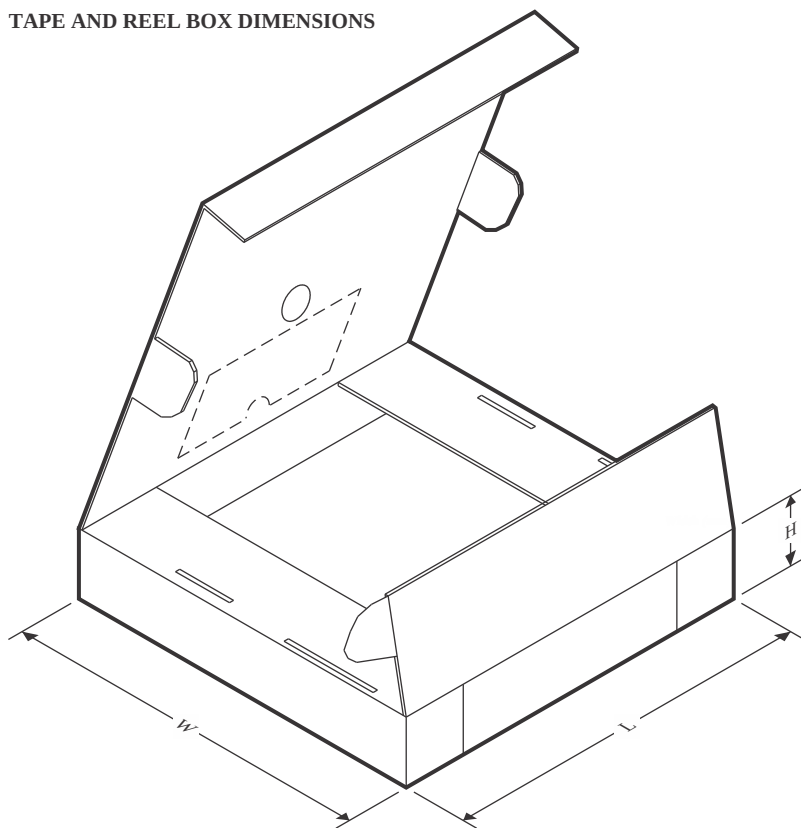
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| OPA134UA/2K5  | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| OPA2134UA/2K5 | SOIC         | D               | 8    | 2500 | 330.0              | 12.4               | 6.4     | 5.2     | 2.1     | 8.0     | 12.0   | Q1            |
| OPA4134UA/2K5 | SOIC         | D               | 14   | 2500 | 330.0              | 16.4               | 6.5     | 9.0     | 2.1     | 8.0     | 16.0   | Q1            |

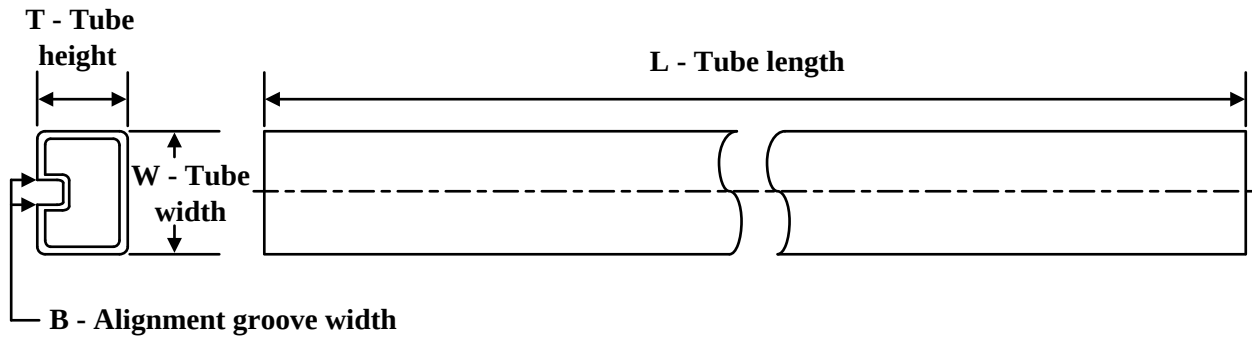
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

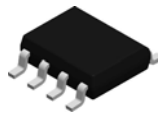
| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| OPA134UA/2K5  | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| OPA2134UA/2K5 | SOIC         | D               | 8    | 2500 | 353.0       | 353.0      | 32.0        |
| OPA4134UA/2K5 | SOIC         | D               | 14   | 2500 | 353.0       | 353.0      | 32.0        |

## TUBE



\*All dimensions are nominal

| Device      | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|-------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| OPA134PA    | P            | PDIP         | 8    | 50  | 506    | 13.97  | 11230  | 4.32   |
| OPA134PA.A  | P            | PDIP         | 8    | 50  | 506    | 13.97  | 11230  | 4.32   |
| OPA134UA    | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| OPA134UA.B  | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| OPA2134PA   | P            | PDIP         | 8    | 50  | 506    | 13.97  | 11230  | 4.32   |
| OPA2134PA.A | P            | PDIP         | 8    | 50  | 506    | 13.97  | 11230  | 4.32   |
| OPA2134PAG4 | P            | PDIP         | 8    | 50  | 506    | 13.97  | 11230  | 4.32   |
| OPA2134UA   | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| OPA2134UA.B | D            | SOIC         | 8    | 75  | 506.6  | 8      | 3940   | 4.32   |
| OPA4134UA   | D            | SOIC         | 14   | 50  | 506.6  | 8      | 3940   | 4.32   |
| OPA4134UA.B | D            | SOIC         | 14   | 50  | 506.6  | 8      | 3940   | 4.32   |

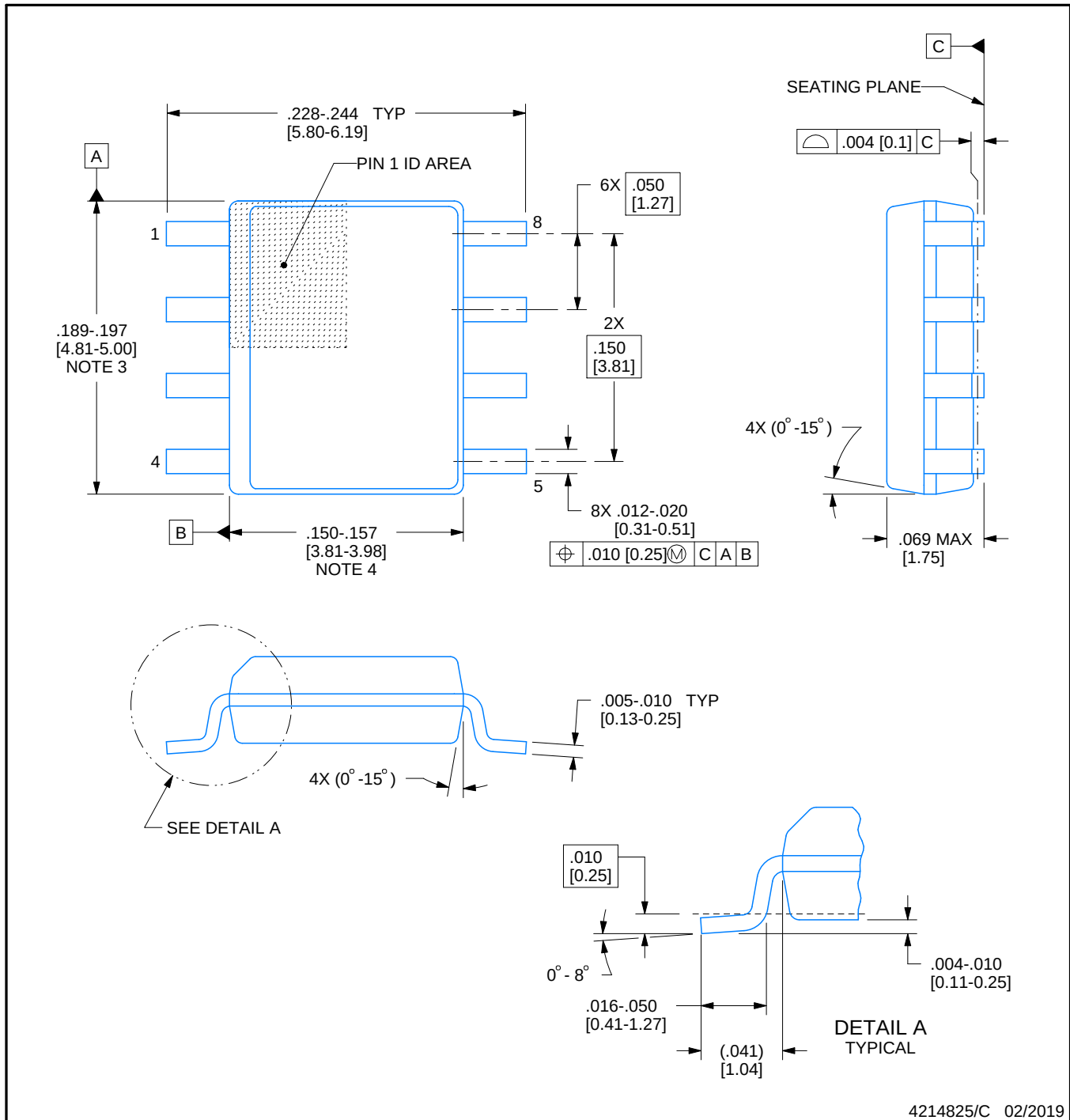


**D0008A**

# PACKAGE OUTLINE

**SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

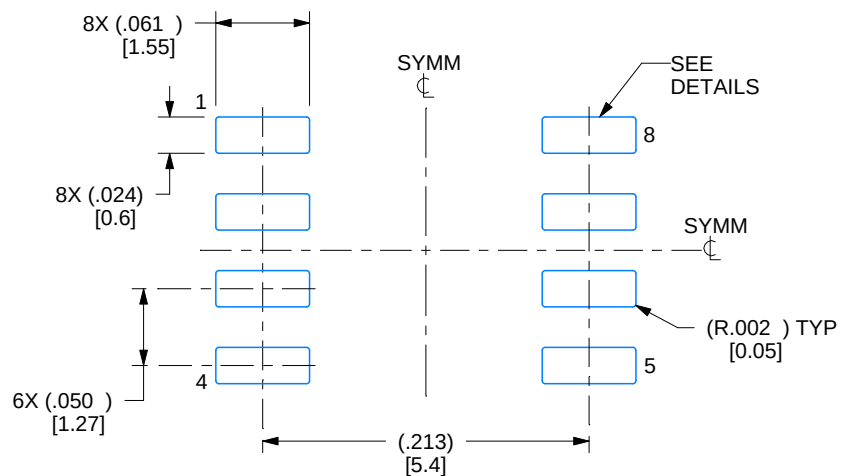
## NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

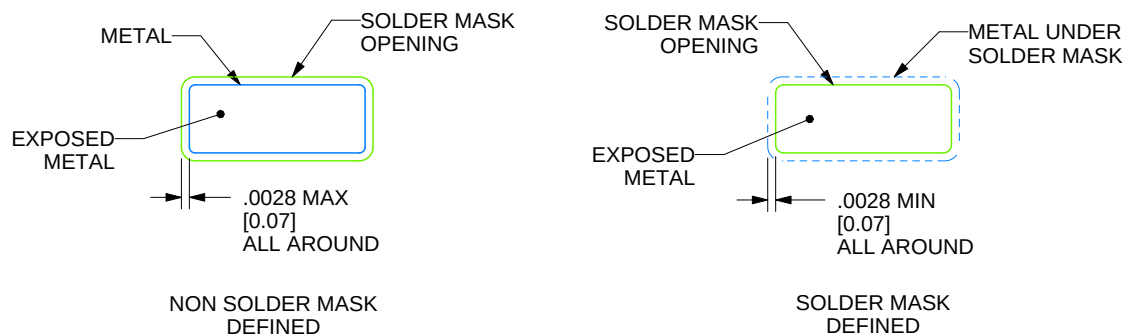
**D0008A**

**SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



## SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

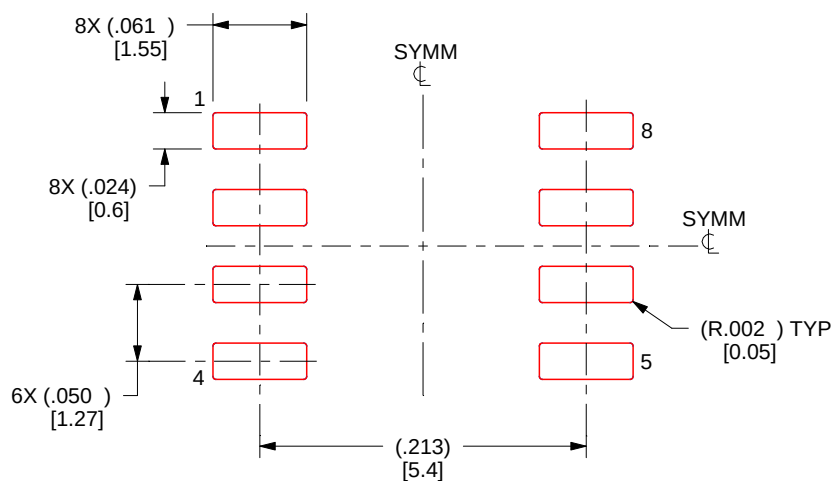
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

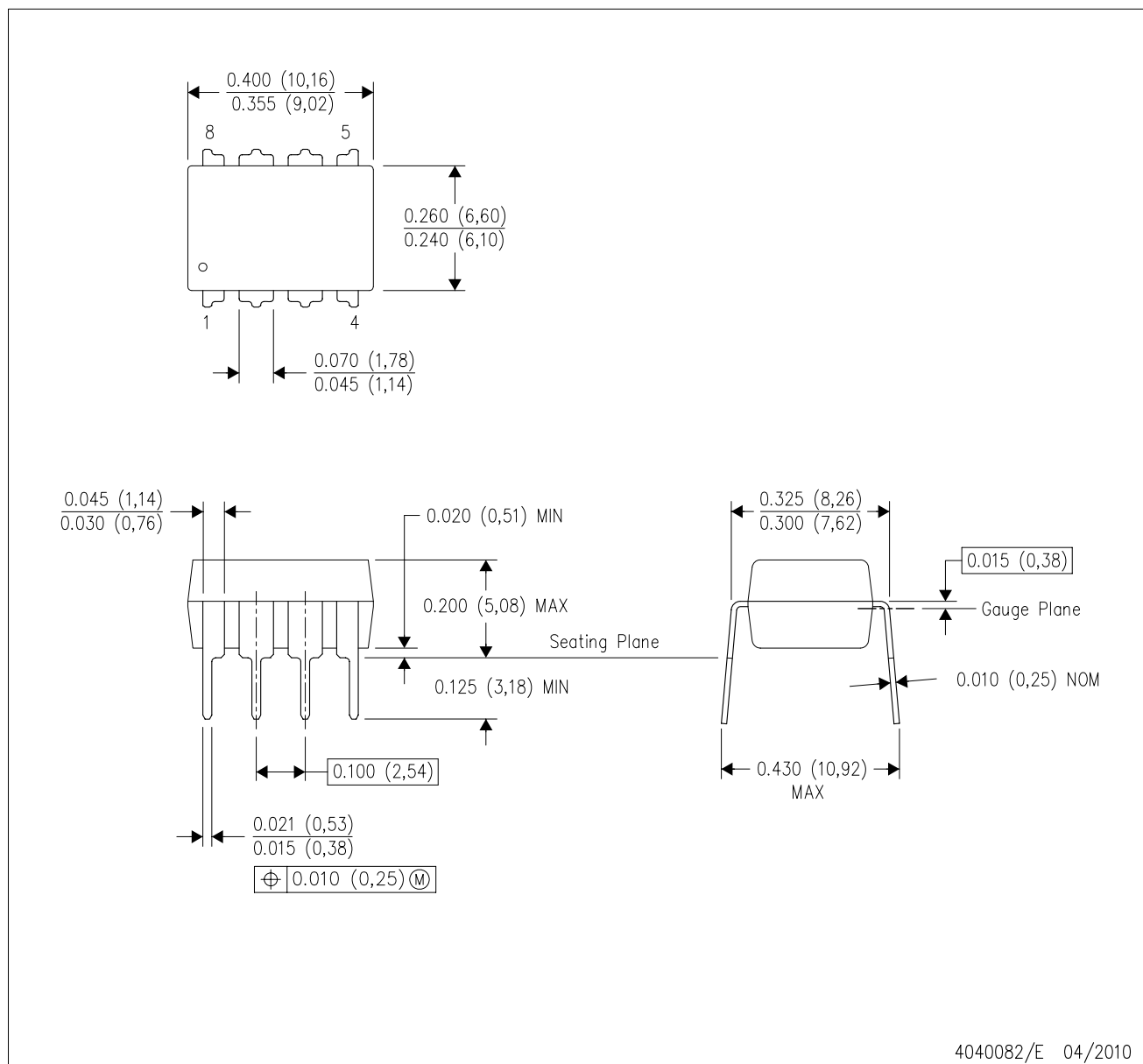
4214825/C 02/2019

NOTES: (continued)

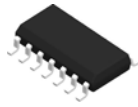
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

P (R-PDIP-T8)

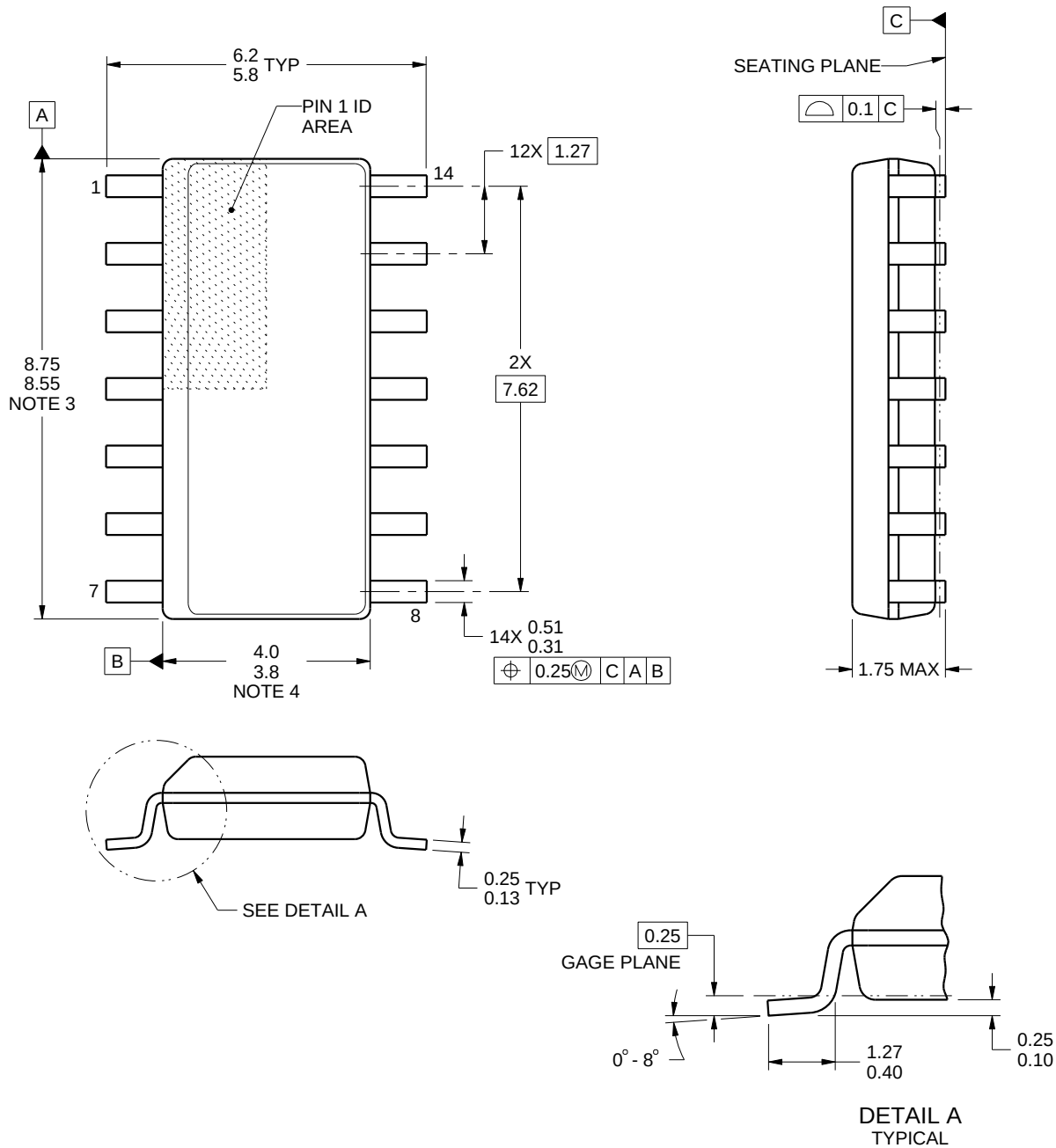
PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
  - B. This drawing is subject to change without notice.
  - C. Falls within JEDEC MS-001 variation BA.

**D0014A****PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

**NOTES:**

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

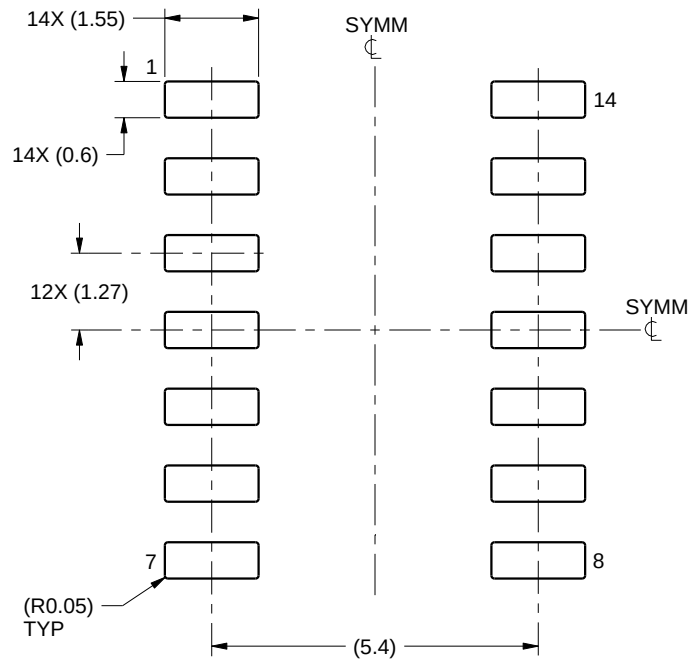


# EXAMPLE BOARD LAYOUT

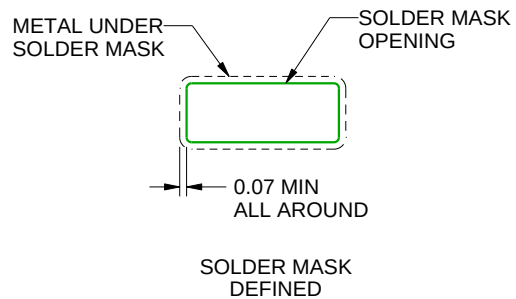
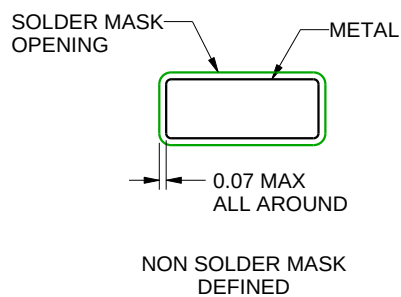
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

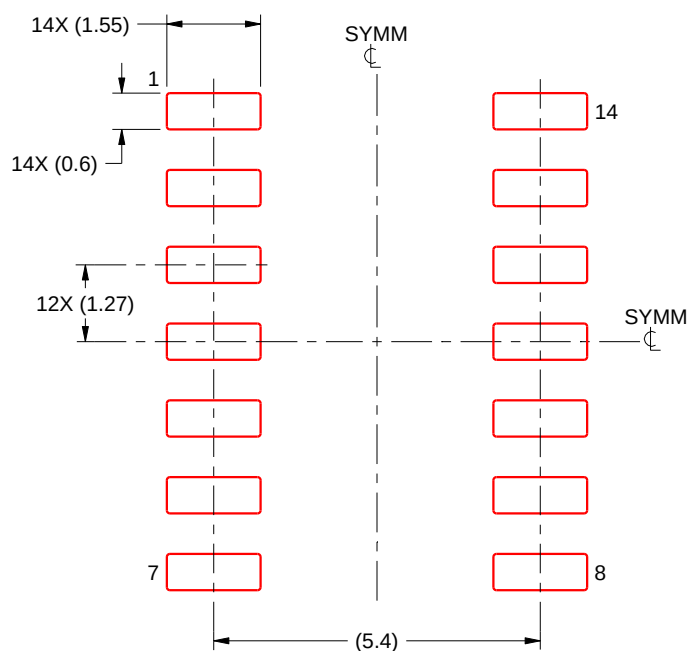
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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